# V30D60C

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Vishay General Semiconductor

# **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.39$  V at  $I_F = 5$  A



#### V30D60C



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 15 A			
V <sub>RRM</sub>	60 V			
I <sub>FSM</sub>	170 A			
$V_F$ at $I_F$ = 15 A	0.57 V			
T <sub>J</sub> max. 150 °C				
Package TO-263AC (SMPD)				
Diode variations	Common cathode			

### FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- AEC-Q101 qualified
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	V30D60C	UNIT
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	60	V
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	30	Α
	per diode		15	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	170	А
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	- 40 to + 150	°C

ROHS COMPLIANT HALOGEN

1

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> (1)	0.47	-	V	
	I <sub>F</sub> = 7.5 A			0.51	-		
	I <sub>F</sub> = 15 A			0.60	0.70		
	$I_F = 5 A$	T <sub>A</sub> = 125 °C		0.38	-		
	I <sub>F</sub> = 7.5 A			0.44	-		
	I <sub>F</sub> = 15 A			0.57	0.65		
Reverse current per diode	$\mathcal{N} = 60 \mathcal{N}$	$V_{\rm R} = 60 \text{ V}$ $\frac{T_{\rm A} = 25 \text{ °C}}{T_{\rm A} = 125 \text{ °C}}$	I <sub>R</sub> <sup>(2)</sup>	-	1200	μA	
	$v_{\rm R} = 00 v$			17	60	mA	

Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER		SYMBOL	V30D60C	UNIT
Typical thermal resistance	per diode	$R_{ ext{ heta}JC}$	2.5	°C/W
	per device		1.7	
	per device	R <sub>0JA</sub> (1)(2)	48	

#### Notes

 $^{(1)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

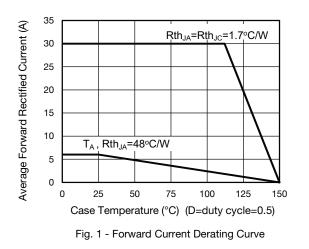
<sup>(2)</sup> Free air, without heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AC (SMPD)	V30D60C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel
TO-263AC (SMPD)	V30D60CHM3/I (1)	0.55	l	2000/reel	13" diameter plastic tape and reel

Note

(1) AEC-Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)



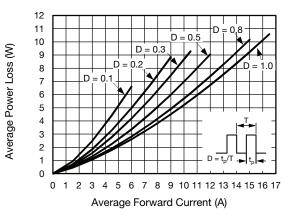


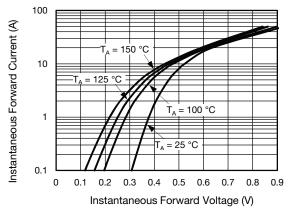
Fig. 2 - Forward Power Loss Characteristics Per Diode

Revision: 09-Dec-13

2

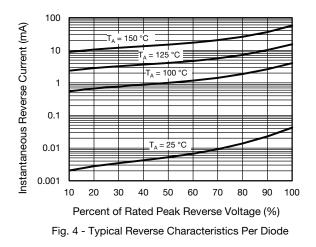
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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



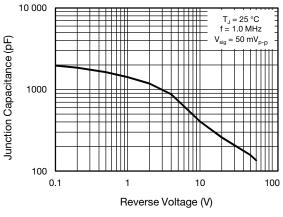
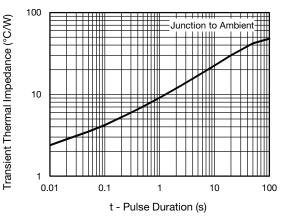
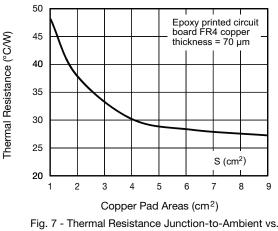


Fig. 5 - Typical Junction Capacitance Per Diode







Copper Pad Areas

Revision: 09-Dec-13

3

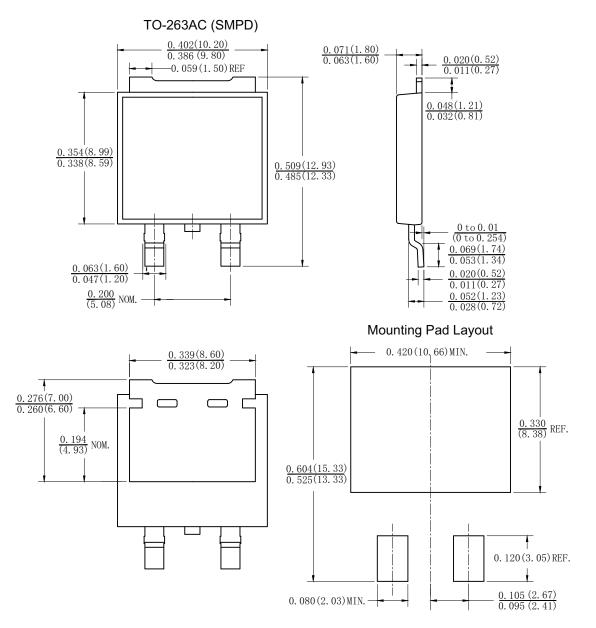
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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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